2-input NAND gate; open drain Rev. 2 — 9 December 2016

Product data sheet

#### **General description** 1.

The 74LVC1G38-Q100 provides a 2-input NAND function.

Inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device as translator in a mixed 3.3 V and 5 V environment.

This device is fully specified for partial power-down applications using IOFF. The IOFF circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1) Specified from –40 °C to +85 °C and from –40 °C to +125 °C
- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant outputs for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
  - ◆ JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8-B/JESD36 (2.7 V to 3.6 V).
- $\pm 24$  mA output drive (V<sub>CC</sub> = 3.0 V)
- CMOS low power consumption
- Open drain outputs
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)

# nexperia

-

2-input NAND gate; open drain

# 3. Ordering information

| Table 1. Ordering information |                   |        |   |          |  |  |  |  |
|-------------------------------|-------------------|--------|---|----------|--|--|--|--|
| Type number                   | Package           |        |   |          |  |  |  |  |
|                               | Temperature range | Name   | Description   | Version  |  |  |  |  |
| 74LVC1G38GW-Q100              | –40 °C to +125 °C | TSSOP5 | plastic thin shrink small outline package; 5 leads;<br>body width 1.25 mm | SOT353-1 |  |  |  |  |
| 74LVC1G38GV-Q100              | –40 °C to +125 °C | SC-74A | plastic surface-mounted package; 5 leads                                  | SOT753   |  |  |  |  |

# 4. Marking

| Type number      | Marking code <sup>[1]</sup> |
|------------------|-----------------------------|
| 74LVC1G38GW-Q100 | YB                          |
| 74LVC1G38GV-Q100 | YB                          |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

# 5. Functional diagram



# 6. Pinning information

### 6.1 Pinning



### 6.2 Pin description

| Table 3. Pin description |     |                |  |  |  |  |
|--------------------------|-----|----------------|--|--|--|--|
| Symbol                   | Pin | Description    |  |  |  |  |
| A                        | 1   | data input     |  |  |  |  |
| В                        | 2   | data input     |  |  |  |  |
| GND                      | 3   | ground (0 V)   |  |  |  |  |
| Y                        | 4   | data output    |  |  |  |  |
| V <sub>CC</sub>          | 5   | supply voltage |  |  |  |  |

# 7. Functional description

#### Table 4. Function table<sup>[1]</sup>

| Input | Output |   |
|-------|--------|---|
| Α     | В      | Y |
| L     | L      | Z |
| L     | Н      | Z |
| н     | L      | Z |
| Н     | Н      | L |

[1] H = HIGH voltage level; L = LOW voltage level; Z = high-impedance OFF state.

# 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

|                  |                         |   | , 0        |      |      | ,    |  |
|------------------|-------------------------|---|------------|------|------|------|--|
| Symbol           | Parameter               | Conditions                                      |            | Min  | Max  | Unit |  |
| V <sub>CC</sub>  | supply voltage          |   |            | -0.5 | +6.5 | V    |  |
| I <sub>IK</sub>  | input clamping current  | V <sub>I</sub> < 0 V                            |            | -50  | -    | mA   |  |
| VI               | input voltage           |   | <u>[1]</u> | -0.5 | +6.5 | V    |  |
| I <sub>OK</sub>  | output clamping current | $V_{\rm O}$ > $V_{\rm CC}$ or $V_{\rm O}$ < 0 V |            | -    | ±50  | mA   |  |
| Vo               | output voltage          | Active mode                                     | [1][2]     | -0.5 | +6.5 | V    |  |
|                  |                         | Power-down mode                                 | [1][2]     | -0.5 | +6.5 | V    |  |
| I <sub>O</sub>   | output current          | $V_{O} = 0 V$ to $V_{CC}$                       |            | -    | ±50  | mA   |  |
| I <sub>CC</sub>  | supply current          |   |            | -    | 100  | mA   |  |
| I <sub>GND</sub> | ground current          |   |            | -100 | -    | mA   |  |
| T <sub>stg</sub> | storage temperature     |   |            | -65  | +150 | °C   |  |
| P <sub>tot</sub> | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$  | [3]        | -    | 300  | mW   |  |

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When  $V_{CC} = 0 V$  (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For TSSOP5 and SC-74A packages: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

# 9. Recommended operating conditions

| Symbol           | Parameter                 | Conditions                               | Min  | Тур | Max  | Unit |
|------------------|---------------------------|--|------|-----|------|------|
| V <sub>CC</sub>  | supply voltage            |  | 1.65 | -   | 5.5  | V    |
| VI               | input voltage             |  | 0    | -   | 5.5  | V    |
| Vo               | output voltage            | Active mode                              | 0    | -   | 5.5  | V    |
|                  |                           | Disable mode; $V_{CC}$ = 1.65 V to 5.5 V | 0    | -   | 5.5  | V    |
|                  |                           | Power-down mode; $V_{CC} = 0 V$          | 0    | -   | 5.5  | V    |
| T <sub>amb</sub> | ambient temperature       |  | -40  | -   | +125 | °C   |
| Δt/ΔV            | input transition rise and | V <sub>CC</sub> = 1.65 V to 2.7 V        | -    | -   | 20   | ns/V |
|                  | fall rate                 | V <sub>CC</sub> = 2.7 V to 5.5 V         | -    | -   | 10   | ns/V |

#### Table 6. Recommended operating conditions

# **10. Static characteristics**

#### Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol               | Parameter                  | Conditions  | Min                | Тур  | Max                | Unit |
|----------------------|----------------------------|---|--------------------|------|--------------------|------|
| T <sub>amb</sub> = - | 40 °C to +85 °C <u>[1]</u> |   |                    |      |                    |      |
| V <sub>IH</sub>      | HIGH-level input voltage   | V <sub>CC</sub> = 1.65 V to 1.95 V  | $0.65V_{CC}$       | -    | -                  | V    |
|                      |                            | V <sub>CC</sub> = 2.3 V to 2.7 V  | 1.7                | -    | -                  | V    |
|                      |                            | V <sub>CC</sub> = 2.7 V to 3.6 V  | 2.0                | -    | -                  | V    |
|                      |                            | $V_{CC} = 4.5 V \text{ to } 5.5 V$  | 0.7V <sub>CC</sub> | -    | -                  | V    |
| V <sub>IL</sub>      | LOW-level input voltage    | V <sub>CC</sub> = 1.65 V to 1.95 V  | -                  | -    | $0.35V_{CC}$       | V    |
|                      |                            | V <sub>CC</sub> = 2.3 V to 2.7 V  | -                  | -    | 0.7                | V    |
|                      |                            | V <sub>CC</sub> = 2.7 V to 3.6 V  | -                  | -    | 0.8                | V    |
|                      |                            | V <sub>CC</sub> = 4.5 V to 5.5 V  | -                  | -    | 0.3V <sub>CC</sub> | V    |
| V <sub>OL</sub>      | LOW-level output voltage   | $V_{I} = V_{IH} \text{ or } V_{IL}$   | -                  | -    | -                  |      |
|                      |                            | $I_{O}$ = 100 $\mu$ A; $V_{CC}$ = 1.65 V to 5.5 V   | -                  | -    | 0.1                | V    |
|                      |                            | $I_{O} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$   | -                  | -    | 0.45               | V    |
|                      |                            | $I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$  | -                  | -    | 0.3                | V    |
|                      |                            | $I_{O}$ = 12 mA; $V_{CC}$ = 2.7 V   | -                  | -    | 0.4                | V    |
|                      |                            | $I_{O} = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$   | -                  | -    | 0.55               | V    |
|                      |                            | $I_{O} = 32 \text{ mA}; V_{CC} = 4.5 \text{ V}$   | -                  | -    | 0.55               | V    |
| I <sub>I</sub>       | input leakage current      | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V                            | -                  | ±0.1 | ±1                 | μA   |
| I <sub>OZ</sub>      | OFF-state output current   |   | -                  | ±0.1 | ±2                 | μA   |
| I <sub>OFF</sub>     | power-off leakage current  | $V_1 \text{ or } V_0 = 5.5 \text{ V}; V_{CC} = 0 \text{ V}$                                 | -                  | ±0.1 | ±2                 | μA   |
| I <sub>CC</sub>      | supply current             | $V_{I} = 5.5 V \text{ or GND};$<br>$V_{CC} = 1.65 V \text{ to } 5.5 V; I_{O} = 0 \text{ A}$ | -                  | 0.1  | 4                  | μA   |
| $\Delta I_{CC}$      | additional supply current  |   | -                  | 5    | 500                | μA   |
| CI                   | input capacitance          |   | -                  | 2.5  | -                  | pF   |

74LVC1G38\_Q100 Product data sheet

© Nexperia B.V. 2017. All rights reserved

2-input NAND gate; open drain

| Symbol                                | Parameter                 | Conditions   | Min                | Тур | Max                | Unit |
|---------------------------------------|---------------------------|--|--------------------|-----|--------------------|------|
| T <sub>amb</sub> = –                  | 40 °C to +125 °C          |  |                    |     |                    |      |
|                                       | HIGH-level input voltage  | V <sub>CC</sub> = 1.65 V to 1.95 V   | $0.65V_{CC}$       | -   | -                  | V    |
|                                       |                           | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$   | 1.7                | -   | -                  | V    |
|                                       |                           | V <sub>CC</sub> = 2.7 V to 3.6 V   | 2.0                | -   | -                  | V    |
|                                       |                           | V <sub>CC</sub> = 4.5 V to 5.5 V   | 0.7V <sub>CC</sub> | -   | -                  | V    |
| V <sub>IL</sub>                       | LOW-level input voltage   | V <sub>CC</sub> = 1.65 V to 1.95 V   | -                  | -   | $0.35V_{CC}$       | V    |
|                                       |                           | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$   | -                  | -   | 0.7                | V    |
|                                       |                           | V <sub>CC</sub> = 2.7 V to 3.6 V   | -                  | -   | 0.8                | V    |
|                                       |                           | V <sub>CC</sub> = 4.5 V to 5.5 V   | -                  | -   | 0.3V <sub>CC</sub> | V    |
| V <sub>OL</sub> LOW-level output volt | LOW-level output voltage  | $V_{I} = V_{IH} \text{ or } V_{IL}$  | -                  | -   | -                  |      |
|                                       |                           | $I_{O}$ = 100 µA; $V_{CC}$ = 1.65 V to 5.5 V   | -                  | -   | 0.1                | V    |
|                                       |                           | I <sub>O</sub> = 4 mA; V <sub>CC</sub> = 1.65 V  | -                  | -   | 0.70               | V    |
|                                       |                           | $I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$   | -                  | -   | 0.45               | V    |
|                                       |                           | I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 2.7 V  | -                  | -   | 0.60               | V    |
|                                       |                           | I <sub>O</sub> = 24 mA; V <sub>CC</sub> = 3.0 V  | -                  | -   | 0.80               | V    |
|                                       |                           | I <sub>O</sub> = 32 mA; V <sub>CC</sub> = 4.5 V  | -                  | -   | 0.80               | V    |
| I                                     | input leakage current     | V <sub>I</sub> = 5.5 V or GND;<br>V <sub>CC</sub> = 0 V to 5.5 V                                     | -                  | -   | ±1                 | μA   |
| l <sub>oz</sub>                       | OFF-state output current  |  | -                  | -   | ±2                 | μA   |
| OFF                                   | power-off leakage current | $V_1 \text{ or } V_0 = 5.5 \text{ V}; V_{CC} = 0 \text{ V}$  | -                  | -   | ±2                 | μA   |
| lcc                                   | supply current            | $V_{I} = 5.5 \text{ V or GND};$<br>$V_{CC} = 1.65 \text{ V to 5.5 V; }I_{O} = 0 \text{ A}$           | -                  | -   | 4                  | μA   |
| Δl <sub>CC</sub>                      | additional supply current | $V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$<br>$V_{CC} = 2.3 \text{ V}$ to 5.5 V; per pin | -                  | -   | 500                | μA   |

#### Table 7. Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

[1] All typical values are measured at V\_{CC} = 3.3 V and T\_{amb} = 25 °C.

# **11. Dynamic characteristics**

#### Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 6</u>.

| Symbol          | Parameter                     | arameter Conditions  |     | °C to +8             | 5 °C | –40 °C to +125 °C |      | Unit |
|-----------------|-------------------------------|--|-----|----------------------|------|-------------------|------|------|
|                 |                               |  | Min | Typ <mark>[1]</mark> | Max  | Min               | Max  |      |
| t <sub>pd</sub> | propagation delay             | A, B to Y; see Figure 5  |     |                      |      |                   |      |      |
|                 |                               | V <sub>CC</sub> = 1.65 V to 1.95 V                             | 1.0 | 3.0                  | 10.0 | 1.0               | 12.5 | ns   |
|                 |                               | $V_{CC}$ = 2.3 V to 2.7 V                                      | 0.5 | 1.8                  | 6.0  | 0.5               | 7.5  | ns   |
|                 |                               | V <sub>CC</sub> = 2.7 V  | 0.5 | 2.5                  | 5.0  | 0.5               | 6.5  | ns   |
|                 |                               | $V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$             | 0.5 | 2.3                  | 4.5  | 0.5               | 5.7  | ns   |
|                 |                               | $V_{CC} = 4.5 \text{ V} \text{ to } 5.5 \text{ V}$             | 0.5 | 1.5                  | 3.9  | 0.5               | 4.9  | ns   |
| C <sub>PD</sub> | power dissipation capacitance | $V_{CC} = 3.3 \text{ V};$ [3]<br>$V_I = \text{GND to } V_{CC}$ | -   | 6                    | -    | -                 | -    | pF   |

[1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

 $\label{eq:tpd} [2] \quad t_{pd} \text{ is the same as } t_{PZL} \text{ and } t_{PLZ}.$ 

[3]  $C_{PD}$  is used to determine the dynamic power dissipation (P<sub>D</sub> in  $\mu$ W).

 $\mathsf{P}_{D} = C_{\mathsf{PD}} \times V_{CC}{}^2 \times f_i \times \mathsf{N} + \sum (C_L \times V_{CC}{}^2 \times f_o)$  where:

f<sub>i</sub> = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V;

N = number of inputs switching;

# $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

# **12. Waveform and test circuit**



#### Nexperia

# 74LVC1G38-Q100

#### 2-input NAND gate; open drain

| Table 9. Measurement points |                    |                    |                          |  |  |  |
|-----------------------------|--------------------|--------------------|--------------------------|--|--|--|
| Supply voltage              | Input              | Output             |                          |  |  |  |
| V <sub>cc</sub>             | V <sub>M</sub>     | V <sub>M</sub>     | V <sub>X</sub>           |  |  |  |
| 1.65 V to 1.95 V            | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> | V <sub>OL</sub> + 0.15 V |  |  |  |
| 2.3 V to 2.7 V              | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> | V <sub>OL</sub> + 0.15 V |  |  |  |
| 2.7 V                       | 1.5 V              | 1.5 V              | V <sub>OL</sub> + 0.3 V  |  |  |  |
| 3.0 V to 3.6 V              | 1.5 V              | 1.5 V              | V <sub>OL</sub> + 0.3 V  |  |  |  |
| 4.5 V to 5.5 V              | 0.5V <sub>CC</sub> | 0.5V <sub>CC</sub> | V <sub>OL</sub> + 0.3 V  |  |  |  |



Fig 6. Test circuit for measuring switching times

#### Table 10. Test data

| Supply voltage   | Input           | Input Lo                        |       |       | V <sub>EXT</sub>                    |  |
|------------------|-----------------|---------------------------------|-------|-------|-------------------------------------|--|
| V <sub>cc</sub>  | VI              | t <sub>r</sub> , t <sub>f</sub> | CL    | RL    | t <sub>PZL</sub> , t <sub>PLZ</sub> |  |
| 1.65 V to 1.95 V | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF | 1 kΩ  | V <sub>CC</sub>                     |  |
| 2.3 V to 2.7 V   | V <sub>CC</sub> | ≤ 2.0 ns                        | 30 pF | 500 Ω | V <sub>CC</sub>                     |  |
| 2.7 V            | 2.7 V           | ≤ 2.5 ns                        | 50 pF | 500 Ω | V <sub>CC</sub>                     |  |
| 3.0 V to 3.6 V   | 2.7 V           | ≤ 2.5 ns                        | 50 pF | 500 Ω | V <sub>CC</sub>                     |  |
| 4.5 V to 5.5 V   | V <sub>CC</sub> | ≤ 2.5 ns                        | 50 pF | 500 Ω | V <sub>CC</sub>                     |  |

74LVC1G38\_Q100
Product data sheet

# 13. Package outline



#### Fig 7. Package outline SOT353-1 (TSSOP5)

All information provided in this document is subject to legal disclaimers.

74LVC1G38\_Q100



#### Fig 8. Package outline SOT753 (SC-74A)

All information provided in this document is subject to legal disclaimers.

74LVC1G38\_Q100

2-input NAND gate; open drain

# 14. Abbreviations

| Table 11. Abbreviations |   |  |
|-------------------------|---|--|
| Acronym                 | Description                             |  |
| CMOS                    | Complementary Metal-Oxide Semiconductor |  |
| DUT                     | Device Under Test                       |  |
| ESD                     | ElectroStatic Discharge                 |  |
| HBM                     | Human Body Model                        |  |
| MIL                     | Military                                |  |
| MM                      | Machine Model                           |  |
| TTL                     | Transistor-Transistor Logic             |  |

# **15. Revision history**

#### Table 12.Revision history

| Document ID        | Release date   | Data sheet status  | Change notice | Supersedes         |
|--------------------|--|--------------------|---------------|--------------------|
| 74LVC1G38_Q100 v.1 | 20161209   | Product data sheet | -             | 74LVC1G38_Q100 v.1 |
| Modifications:     | • <u>Table 7</u> : The maximum limits for leakage current and supply current have changed. |                    |               |                    |
| 74LVC1G38_Q100 v.1 | 20131127   | Product data sheet | -             | -                  |

# **16. Legal information**

#### 16.1 Data sheet status

| Document status[1][2]          | Product status <sup>[3]</sup> | Definition  |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet   | Development                   | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification                 | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production                    | This document contains the product specification.                                     |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

#### 16.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any

representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and

customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

**Right to make changes** — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

# Suitability for use in automotive applications — This Nexperia product has been qualified for use in automotive

applications. Unless otherwise agreed in writing, the product is not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

#### Terms and conditions of commercial sale - Nexperia

products are sold subject to the general terms and conditions of commercial sale, as published at <a href="http://www.nexperia.com/profile/terms">http://www.nexperia.com/profile/terms</a>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

Rev. 2 — 9 December 2016

#### 2-input NAND gate; open drain

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

#### 16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

# 17. Contact information

For more information, please visit: http://www.nexperia.com

For sales office addresses, please send an email to: salesaddresses@nexperia.com

2-input NAND gate; open drain

### **18. Contents**

| 1    | General description 1              |
|------|------------------------------------|
| 2    | Features and benefits 1            |
| 3    | Ordering information 2             |
| 4    | Marking 2                          |
| 5    | Functional diagram 2               |
| 6    | Pinning information 2              |
| 6.1  | Pinning 2                          |
| 6.2  | Pin description 3                  |
| 7    | Functional description 3           |
| 8    | Limiting values 3                  |
| 9    | Recommended operating conditions 4 |
| 10   | Static characteristics 4           |
| 11   | Dynamic characteristics 6          |
| 12   | Waveform and test circuit          |
| 13   | Package outline                    |
| 14   | Abbreviations                      |
| 15   | Revision history 10                |
| 16   | Legal information 11               |
| 16.1 | Data sheet status 11               |
| 16.2 | Definitions 11                     |
| 16.3 | Disclaimers 11                     |
| 16.4 | Trademarks 12                      |
| 17   | Contact information 12             |
| 18   | Contents 13                        |



Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию.

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России, а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научноисследовательскими институтами России.

С нами вы становитесь еще успешнее!

#### Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург, Промышленная ул, дом № 19, литера Н, помещение 100-Н Офис 331